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TRANSMITTAL LETTER JUN 9 2005 (General - Patent Pending)				Docket No. OKI.612	
In Reapplication of: Kazuhide Abe					
Application No.	Filing Date	Examiner	Customer No.	Group Art Unit	Confirmation No.
10/766,739	January 29, 2004	J. Ingham	20987	2814	2843
Title: WIRING STRUCTURE OF SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME					
		COMMISSIONER FOR PAT	ENTS:		
Transmitted herewith is:					
Response To Restriction Requirement					
 in the above identified application. No additional fee is required. A check in the amount of is attached. The Director is hereby authorized to charge and credit Deposit Account No. 50-0238 as described below. Charge the amount of Credit any overpayment. Charge any additional fee required. Payment by credit card. Form PTO-2038 is attached. WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038. 					
ANDREW J. TELES REG. NO. 33,581	Z, JR.		<u></u>		
VOLENTINE FRANC 11951 FREEDOM D RESTON, VA 2019 TEL. NO. (571) 283	0	C.	deposited with sufficient postag addressed to th	the United States je as first class i	pondence is being Postal Service with mail in an envelope or Patents, P.O. Box 87 CFR 1.8(a)] on
cc:				e of Person Mailing C	orrespondence iling Correspondence



OKI.612 Serial No. 10/766,739

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of

Kazuhide Abe

Group Art Unit: 2814

Examiner: J. Ingham

Serial No.: 10/766,739

Filed: January 29, 2004

Conf. No: 2843

FOR: WIRING STRUCTURE OF SEMICONDUCTOR DEVICE AND METHOD OF MANUFACTURING THE SAME

RESPONSE TO RESTRICTION REQUIREMENT

U.S. Patent and Trademark Office Customer Window, **Mail Stop Amendment** Randolph Building 401 Dulany Street Alexandria, VA 22314

Date: June 9, 2006

Sir:

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In response to the Restriction Requirement dated May 9, 2006, the following

election and remarks are respectfully submitted in connection with the above identified

application.

Remarks/Arguments begin on page 2 of this paper.